NSN 5961-01-049-0900

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-049-0900 **Inclosure Material:** Metal **Overall Length:** 0.012 inches **Terminal Length:** 0.005 inches **Overall Height:** 0.002 inches **Overall Width:** 0.010 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, dc and 1.0 forward voltage, dc **Voltage Tolerance In Percent:** -2.0/+5.0 **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Test Data Document:** 03640-6096600 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure:**